International
IOR Rectifier

IRAMS06UP60B

iMOTION™ Series

Plug N Drive™ Integrated Power Module for Appliance Motor Drive

6A, 600V
with Internal Shunt Resistor

Description

International Rectifier's IRAMS06UP60B is an Integrated Power Module developed and optimized for electronic motor control in appliance applications specifically for VF compressor drives for refrigerators and freezer or in heating and ventilation as electronic fan controls. The IRAMS06UP60B offers an extremely compact, high performance AC motor-driver in a single isolated package for a very simple design.
An internal shunt is included and offers easy current feedback and overcurrent monitor for precise control and safe operation. A built-in temperature monitor and over-current protection, along with the short-circuit rated IGBTs and integrated under-voltage lockout function, deliver high level of protection and fail-safe operation. The integration of the bootstrap diodes for the high-side driver section, and the single polarity power supply required to drive the internal circuitry, simplify the utilization of the module and deliver further cost reduction advantages.

Features

- Internal Shunt Resistor
- Integrated Gate Drivers and Bootstrap Diodes
- Temperature Monitor
- Overcurrent shutdown
- Fully Isolated Package.
- Low $V_{CE(on)}$ Non Punch Through IGBT Technology
- Undervoltage lockout for all channels
- Matched propagation delay for all channels
- Schmitt-triggered input logic
- Cross-conduction prevention logic
- Lower di/dt gate driver for better noise immunity
- Motor Power range 0.1~0.5kW / 85~253 Vac
- Isolation 2000V_{RMS} /1min

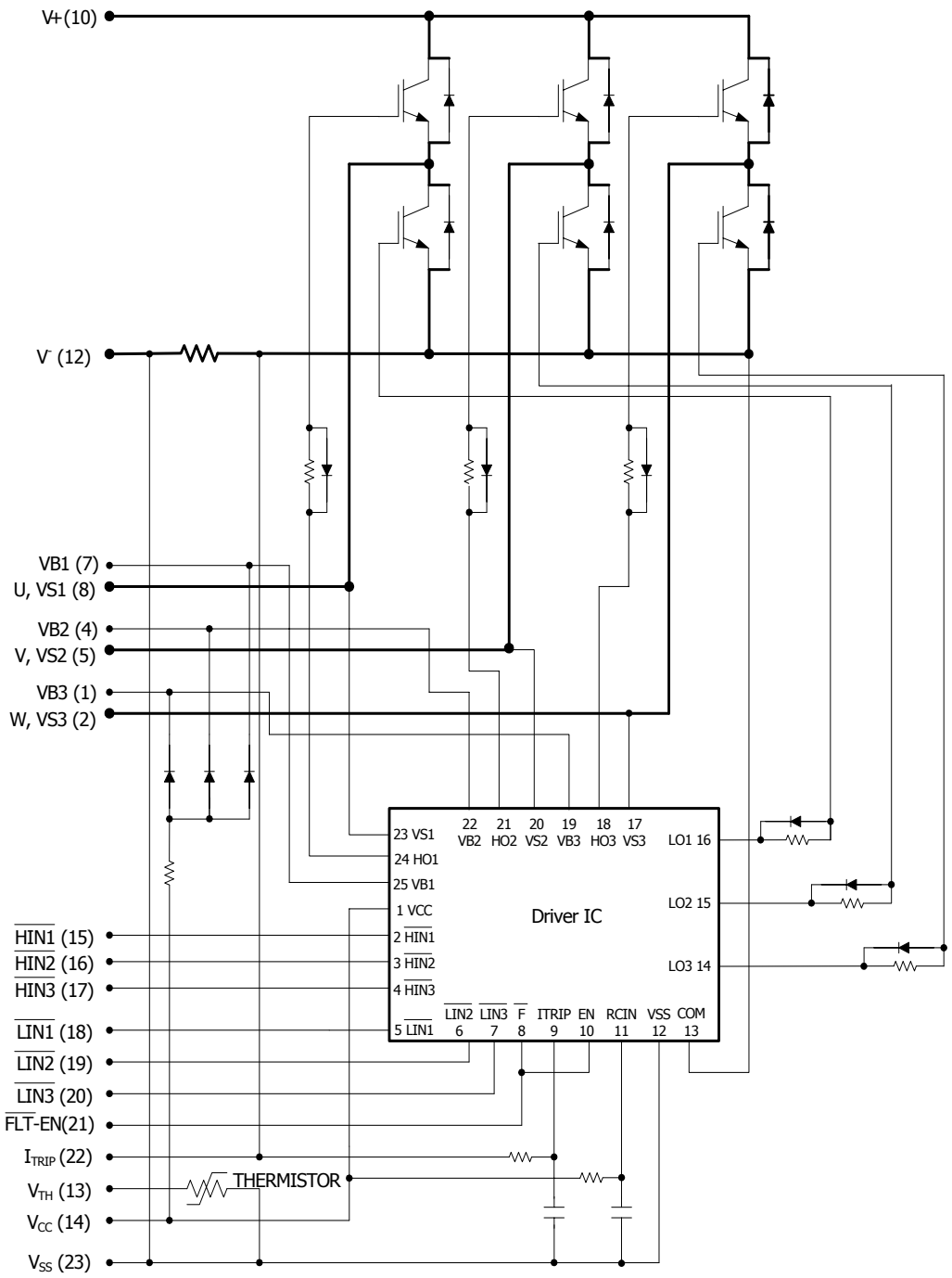


Absolute Maximum Ratings

Parameter	Description	Max. Value	Units
V_{CES}	Maximum IGBT Blocking Voltage	600	V
V^+	Positive Bus Input Voltage	450	
I_o @ T_C=25°C	RMS Phase Current	6	A
I_o @ T_C=100°C	RMS Phase Current	3	
I_{pk}	Max Peak Phase Current (tp<100ms) (see Note 1)	9	
F_p	Maximum PWM Carrier Frequency	20	kHz
P_d	Maximum Power dissipation per Phase	7.5	W
V_{iso}	Isolation Voltage (1min)	2000	V_{RMS}
$T_{J\ (IGBT\ \&\ Diodes)}$	Operating Junction temperature Range	-40 to +150	°C
$T_{J\ (Driver\ IC)}$	Operating Junction temperature Range	-40 to +150	
T	Mounting torque Range (M3 screw)	0.8 to 1.0	Nm

Note 1: Limited by current protection, see table "Inverter Section Electrical Characteristics" on page 3

Internal Electrical Schematic - IRAMS06UP60B



Inverter Section Electrical Characteristics @ T_J = 25°C

Symbol	Parameter	Min	Typ	Max	Units	Conditions
$V_{(BR)CES}$	Collector-to-Emitter Breakdown Voltage	600	---	---	V	V_{IN}=5V, I_C=250µA
$\Delta V_{(BR)CES}$ / ΔT	Temperature Coeff. Of Breakdown Voltage	---	0.3	---	V/°C	V_{IN}=5V, I_C=1.0mA (25°C - 150°C)
$V_{CE(ON)}$	Collector-to-Emitter Saturation Voltage	---	1.9	2.4	V	I_C=3A, V_{DD}=15V
		---	2.2	2.6		I_C=3A, V_{DD}=15V, T_J=150°C
I_{CES}	Zero Gate Voltage Collector-to-Emitter Current	---	15	45	µA	V_{IN}=5V, V^+=600V
		---	60	170		V_{IN}=5V, V^+=600V, T_J=150°C
I_{lk_module}	Zero Gate Phase-to-Phase Current	--	--	50	µA	V_{IN}=5V, V^+=600V
V_{FM}	Diode Forward Voltage Drop	---	1.45	1.85	V	I_C=3A
		---	1.25	1.65		I_C=3A, T_J=150°C
I_{BUS_Trip}	Current Protection Threashold (positive going)	8.5	---	10.5	A	T_j=-40°C to 150°C (Overcurrent duration ≥ 6µs)

Inverter Section Switching Characteristics @ T_J = 25°C

Symbol	Parameter	Min	Typ	Max	Units	Conditions
E_{on}	Turn-On Switching Loss	---	130	235	µJ	I_C=3A, V^+=400V
E_{off}	Turn-Off Switching Loss	---	65	120		V_{DD}=15V, L=1mH
E_{tot}	Total Switching Loss	---	195	355		See CT1 T_J=25°C
E_{on}	Turn-on Swtiching Loss	---	200	345	µJ	See CT1 T_J=150°C
E_{off}	Turn-off Switching Loss	---	90	150		Energy losses include "tail" and
E_{tot}	Total Switching Loss	---	290	495		diode reverse recovery
E_{rec}	Diode Rev. Recovery energy	---	50	110	µJ	T_J=150°C, V^+ =400V V_{DD}=15V,
t_{rr}	Diode Reverse Recovery time	---	150	200	ns	I_F=3A, L=1mH
RBSOA	Reverse Bias Safe Operating Area	FULL SQUARE				T_J=150°C, I_C=3A, V_P=600V V^+=480V, V_{DD}=+15V to 0V See CT3
SCSOA	Short Circuit Safe Operating Area	10	---	---	µs	T_J=150°C, V_P=600V, V^+=360V, V_{DD}=+15V to 0V See CT2

Thermal Resistance

Symbol	Parameter	Min	Typ	Max	Units	Conditions
$R_{th(J-C)}$	Junction to case thermal resistance, each IGBT under inverter operation.	---	---	6.5	°C/W	Flat, greased surface. Heatsink compound thermal conductivity - 1W/mK
$R_{th(J-C)}$	Junction to case thermal resistance, each Diode under inverter operation.	---	---	9	°C/W	
$R_{th(C-S)}$	Case to sink thermal resistance	---	0.1	---	°C/W	

Absolute Maximum Ratings Driver Function

Absolute Maximum Ratings indicate substained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to V_{SS} . (Note 2)

Symbol	Definition	Min	Max	Units
$V_{S1,2,3}$	High Side offset voltage	-0.3	600	V
$V_{B1,2,3}$	High Side floating supply voltage	-0.3	20	V
V_{DD}	Low Side and logic fixed supply voltage	-0.3	20	V
V_{IN}	Input voltage LIN, HIN, T/I_{TRIP}	-0.3	V_{SS}+15	V
T_J	Juction Temperature	-40	150	°C

Recommended Operating Conditions Driver Function

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. All voltages are absolute referenced to V_{SS}. The V_S offset is tested with all supplies biased at 15V differential (Note 2). All input pin (V_{IN}) and I_{TRIP} are clamped with a 5.2V zener diode and pull-up resistor to V_{DD}.

Symbol	Definition	Min	Max	Units
$V_{B1,2,3}$	High side floating supply voltage	V_S+12	V_S+20	V
$V_{S1,2,3}$	High side floating supply offset voltage	Note 3	450	
V_{DD}	Low side and logic fixed supply voltage	12	20	V
V_{IN}	Logic input voltage LIN, HIN	V_{SS}	V_{SS}+5	V

Static Electrical Characteristics Driver Function

V_{BIAS} (V_{DD}, $V_{BS1,2,3}$)=15V, unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to V_{SS} and are applicable to all six channels. (Note 2)

Symbol	Definition	Min	Typ	Max	Units
$V_{IN,th+}$	Positive going input threshold	3.0	---	---	V
$V_{IN,th-}$	Negative going input threshold	---	---	0.8	V
V_{CCUV+} V_{BSUV+}	V_{CC} and V_{BS} supply undervoltage Positive going threshold	10.6	11.1	11.6	V
V_{CCUV-} V_{BSUV-}	V_{CC} and V_{BS} supply undervoltage Negative going threshold	10.4	10.9	11.4	V
V_{CCUVH} V_{BSUVH}	V_{CC} and V_{BS} supply undervoltage $I_{lockout}$ hysteresis	---	0.2	---	V
I_{QBS}	Quiescent V_{BS} supply current	---	70	120	µA
I_{QCC}	Quiscent V_{CC} supply current	---	1.6	2.3	mA
I_{LK}	Offset Supply Leakage Current	---	---	50	µA
I_{IN+}	Input bias current (OUT=LO)	---	100	220	µA
I_{IN+}	Input bias current (OUT=HI)	---	200	300	µA
$V(I_{TRIP})$	I_{TRIP} threshold Voltage (OUT=HI or OUT=LO)	0.44	0.49	0.54	V

Dynamic Electrical Characteristics

V_{DD}=V_{BS}=V_{BIAS}=15V, PWM_{IN}=2kHz, V_{IN_ON}=V_{IN_th+}, V_{IN_OFF}=V_{IN_th-}
T_A=25°C, unless otherwise specified

Symbol	Definition	Min	Typ	Max	Units
T_{ON}	Input to output propagation turn-on delay time (see fig.11)	-	470	-	ns
T_{OFF}	Input to output propagation turn-off delay time (see fig. 11)	-	615	-	ns
D_T	Dead Time	-	290	-	ns
I/T_{Trip}	T/I_{Trip} to six switch to turn-off propagation delay (see fig. 2)	-	750	-	ns
T_{FCLTRL}	Post I_{Trip} to six switch to turn-off clear time (see fig. 2)	-	9	-	ms

Internal NTC - Thermistor Characteristics

Parameter		Typ	Units	Conditions
R_{25}	Resistance	100 +/- 3%	kΩ	T_C = 25°C
R_{125}	Resistance	2.522 ±10.9%	kΩ	T_C = 125°C
B	B-constant (25-50°C)	4250 +/- 2%	k	$R_2 = R_1 e^{[B(1/T2 - 1/T1)]}$
Temperature Range		-40 / 125	°C	
Typ. Dissipation constant		1	mW/°C	T_C = 25°C

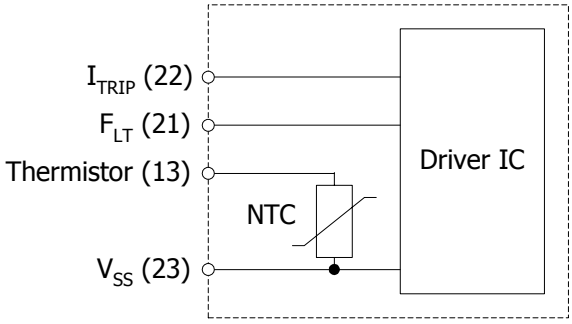
Internal Current Sensing Resistor - Shunt Characteristics

Parameter		Units
Resistance	50 ±1%	mΩ
Tollerance	±1%	
Max Power Dissipation	1.5	W
Temperature Range	-40 / 125	°C

Note 2: For more details, see IR21363 data sheet

Note 3: Logic operational for V_S from V^- -5V to V^- +600V. Logic state held for V_S from V^- -5V to V^- -V_{BS}. (please refer to DT97-3 for more details)

Thermistor Built-in IRAMS06UP60B



Note 4: The Maximum recommended sense voltage at the I_{TRIP} terminal under normal operating conditions is 3.3V.

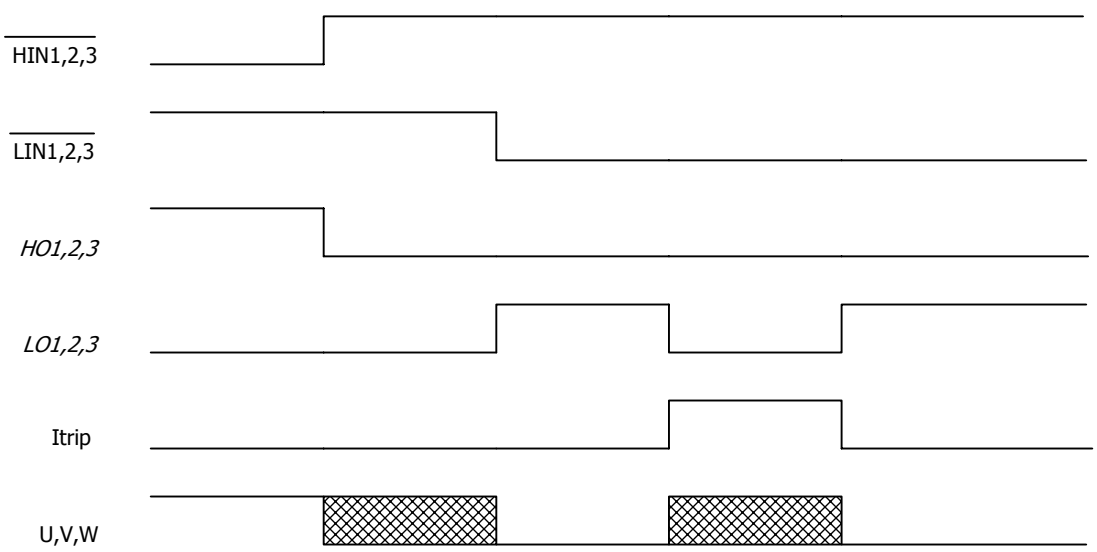
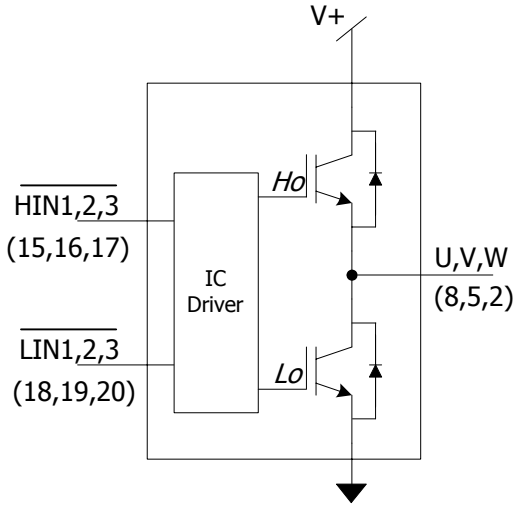
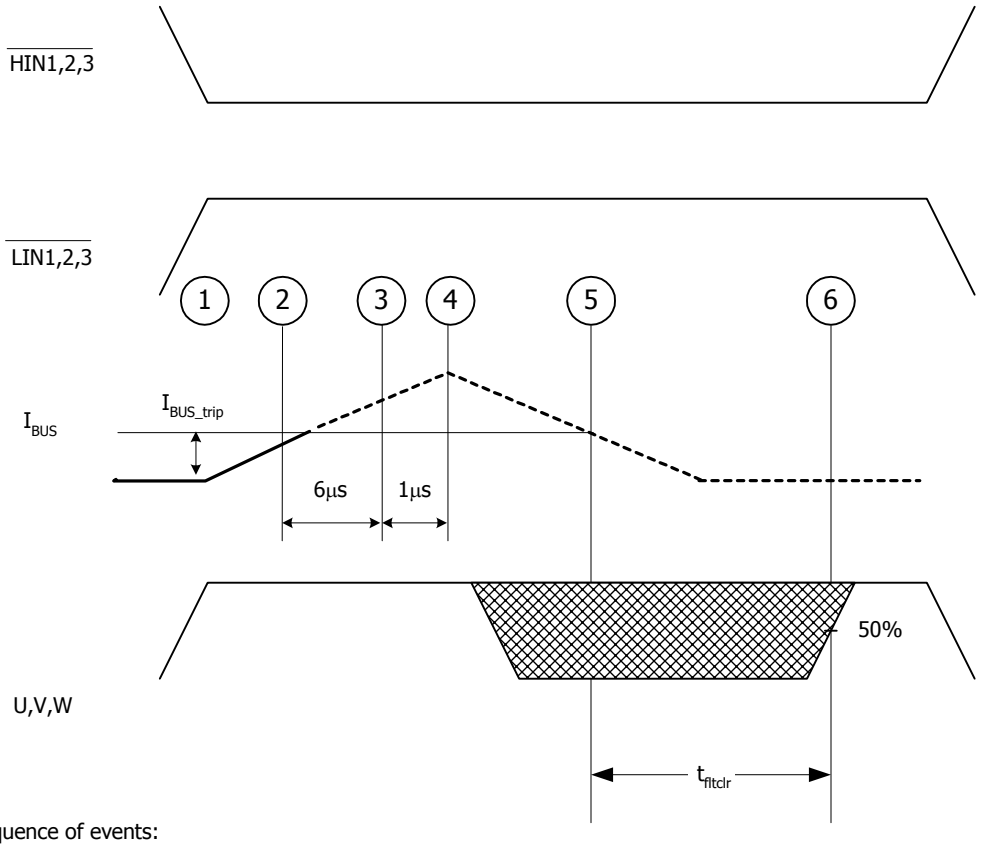


Figure1. Input/Output Timing Diagram

Note 5: The shaded area indicates that both high-side and low-side switches are off and therefore the half-bridge output voltage would be determined by the direction of current flow in the load.



Itrip	$\overline{\text{HIN1,2,3}}$	$\overline{\text{LIN1,2,3}}$	U,V,W
0	0	1	V+
0	1	0	0
0	1	1	X
1	X	X	X



Sequence of events:
1-2) Current begins to rise
2) Current reaches I_{BUS_Trip} level
2-3) Current is higher than I_{BUS_Trip} for at least 6µs. This value is the worst-case condition with very low over-current. In case of high current (short circuit), the actual delay will be smaller.
3-4) Delay between driver identification of over-current condition and disabling of all outputs
4) Current starts decreasing, eventually reaching 0
5) Current goes below I_{BUS_trip}, the driver starts its auto-reset sequence
6) Driver is automatically reset and normal operation can resume (over-current condition must be removed by the time the drivers automatically resets itself)

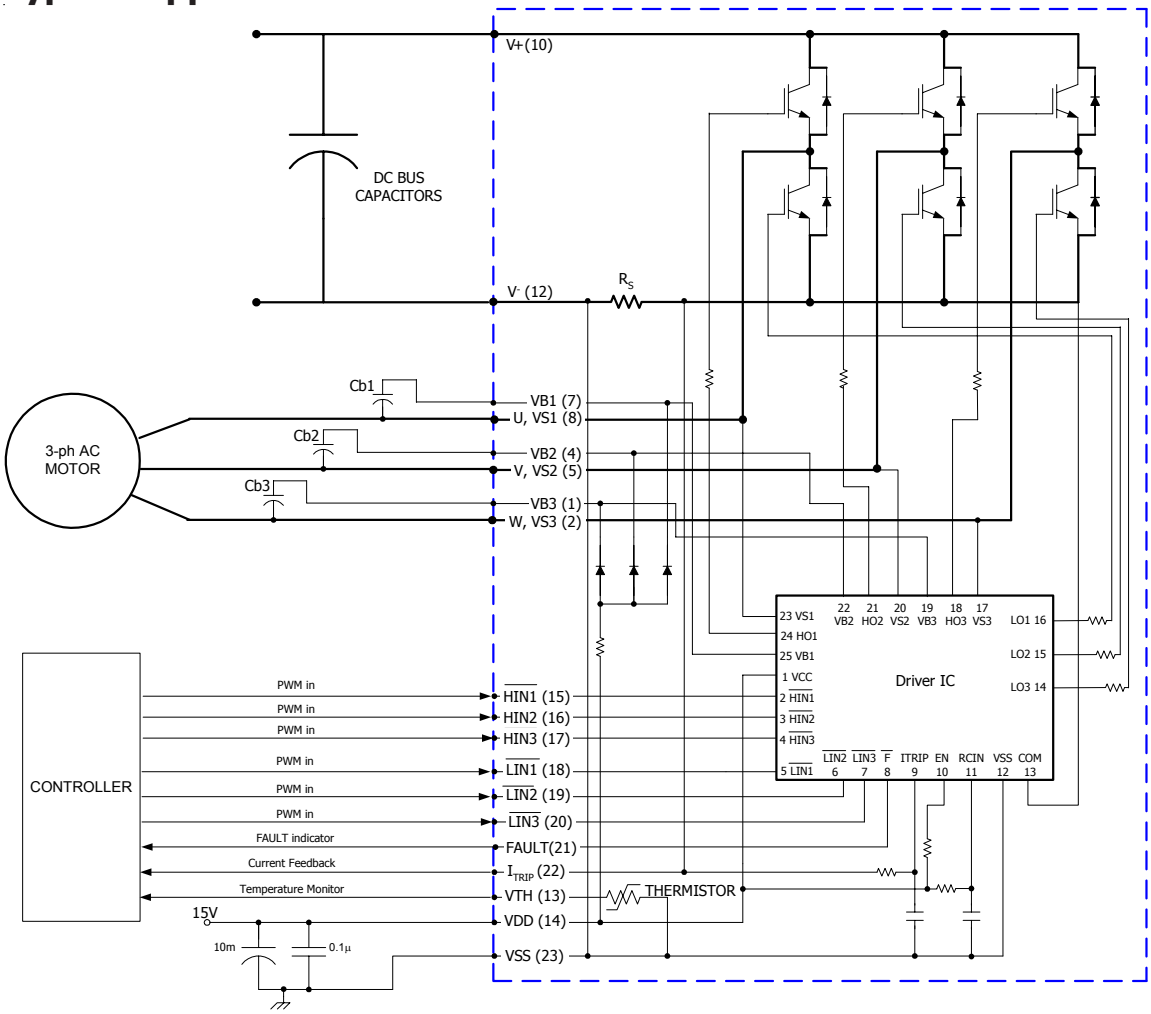
Figure 2. I_{Trip} Timing Waveform

Note 6: The shaded area indicates that both high-side and low-side switches are off and therefore the half-bridge output voltage would be determined by the direction of current flow in the load.

Module Pin-Out Description

Pin	Name	Description
1	V_{B3}	High Side Floating Supply Voltage 3
2	W,V_{S3}	Output 3 - High Side Floating Supply Offset Voltage
3	NA	none
4	V_{B2}	High Side Floating Supply voltage 2
5	V,V_{S2}	Output 2 - High Side Floating Supply Offset Voltage
6	NA	none
7	V_{B1}	High Side Floating Supply voltage 1
8	U, V_{S1}	Output 1 - High Side Floating Supply Offset Voltage
9	NA	none
10	V^+	Positive Bus Input Voltage
11	NA	none
12	V^-	Negative Bus Input Voltage
13	V_{TH}	Temperature Feedback
14	V_{CC}	+15V Main Supply
15	$\overline{H_{IN1}}$	Logic Input High Side Gate Driver - Phase 1
16	$\overline{H_{IN2}}$	Logic Input High Side Gate Driver - Phase 2
17	$\overline{H_{IN3}}$	Logic Input High Side Gate Driver - Phase 3
18	$\overline{L_{IN1}}$	Logic Input Low Side Gate Driver - Phase 1
19	$\overline{L_{IN2}}$	Logic Input Low Side Gate Driver - Phase 2
20	$\overline{L_{IN3}}$	Logic Input Low Side Gate Driver - Phase 3
21	$\overline{FLT}$/Enable	Fault Output and Enable Pin
22	I_{TRIP}	Current Sense and Itrip Pin
23	V_{SS}	Negative Main Supply

Typical Application Connection IRAMS06UP60B



1. Electrolytic bus capacitors should be mounted as close to the module bus terminals as possible to reduce ringing and EMI problems. Additional high frequency ceramic capacitor mounted close to the module pins will further improve performance.

2. In order to provide good decoupling between V_{CC}-Gnd and V_B-V_{SS} terminals, the capacitors shown connected between these terminals should be located very close to the module pins. Additional high frequency capacitors, typically 0.1µF, are strongly recommended.

3. Value of the boot-strap capacitors depends upon the switching frequency. Their selection should be made based on IR design tip DN 98-2a, application note AN-1044 or Figure 9.

4. Current sense signal can be obtained from pin 22 and pin 23

5. After approx. 9 ms the FAULT is reset

6.PWM generator must be disabled within Fault duration to garantee shutdown of the system, overcurrent condition must be cleared before resuming operation

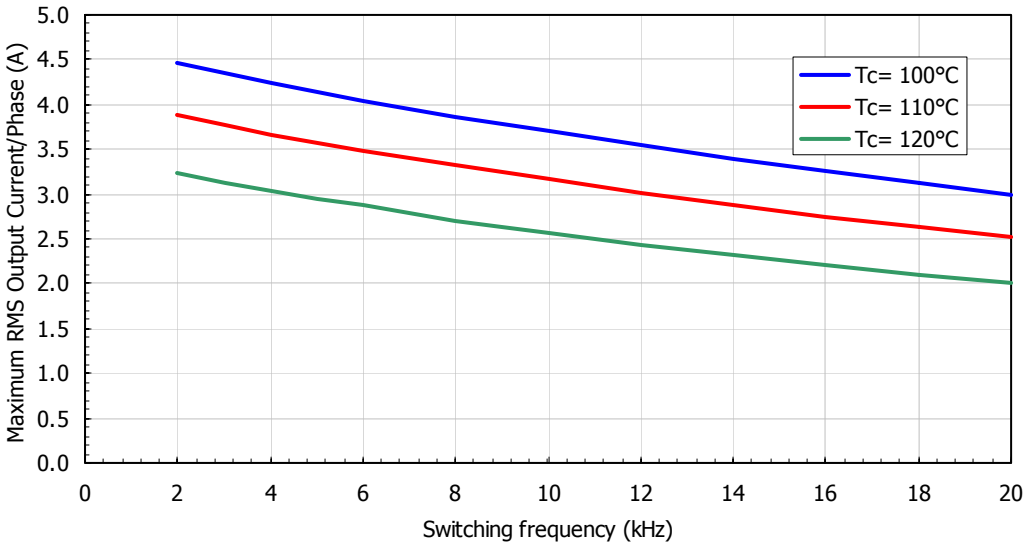


Figure 3. Maximum sinusoidal phase current as function of switching frequency
V+ = 400V, T_j=150°C, Modulation Depth=0.8, PF=0.6

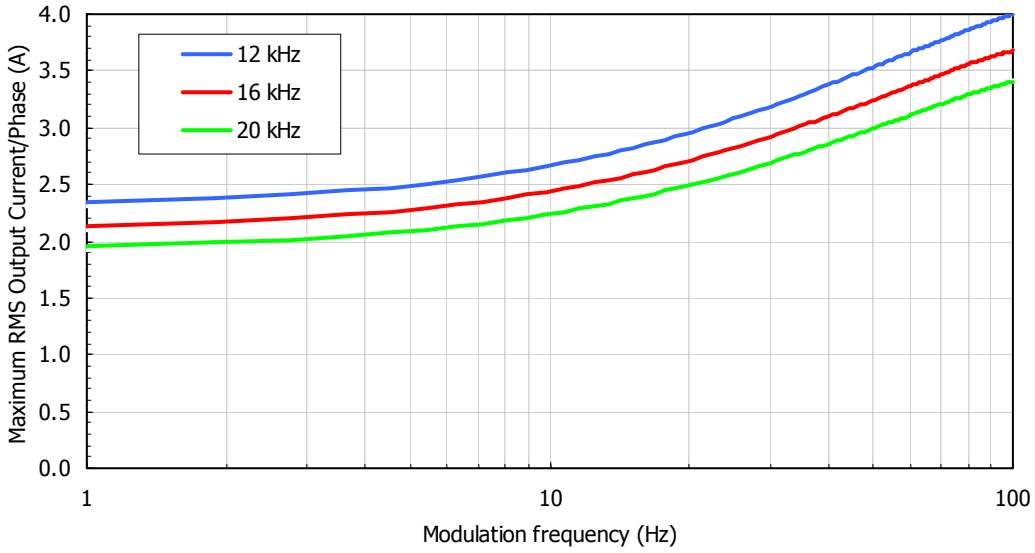


Figure 4. Maximum sinusoidal phase current as function of modulation frequency
V+=400V, T_j=150°C, T_c=100°C, Modulation Depth=0.8, PF=0.6

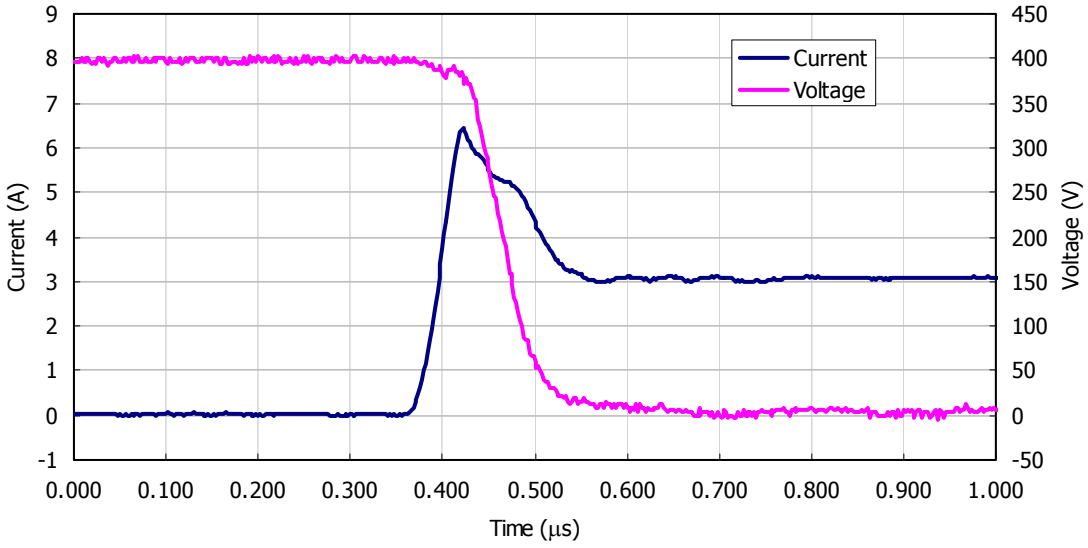


Figure 5. IGBT Turn-on. Typical turn-on waveform @T_j=125°C, V+=400V

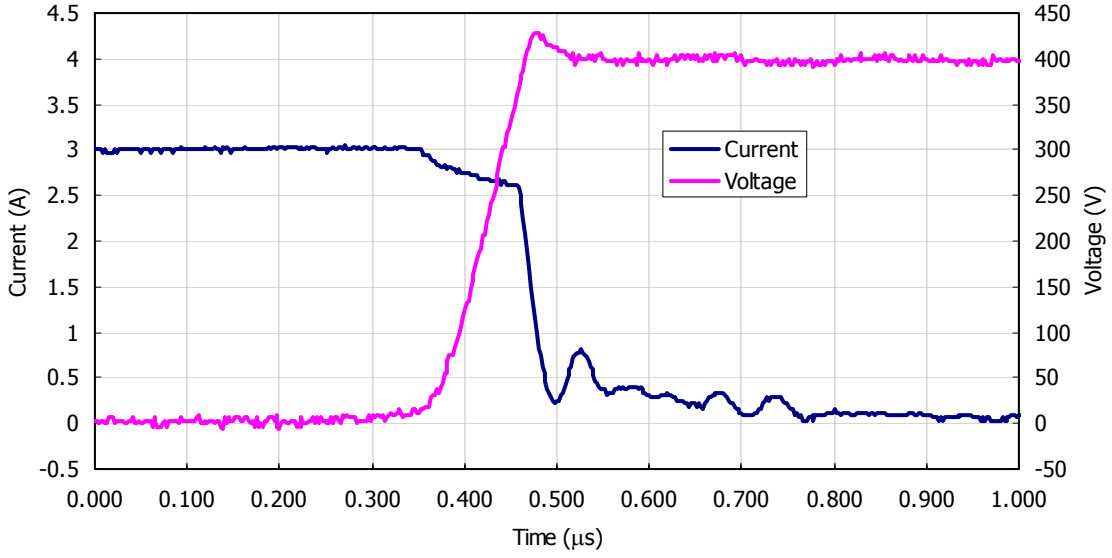


Figure 6. IGBT Turn-off. Typical turn-off waveform @T_j=125°C, V+=400V

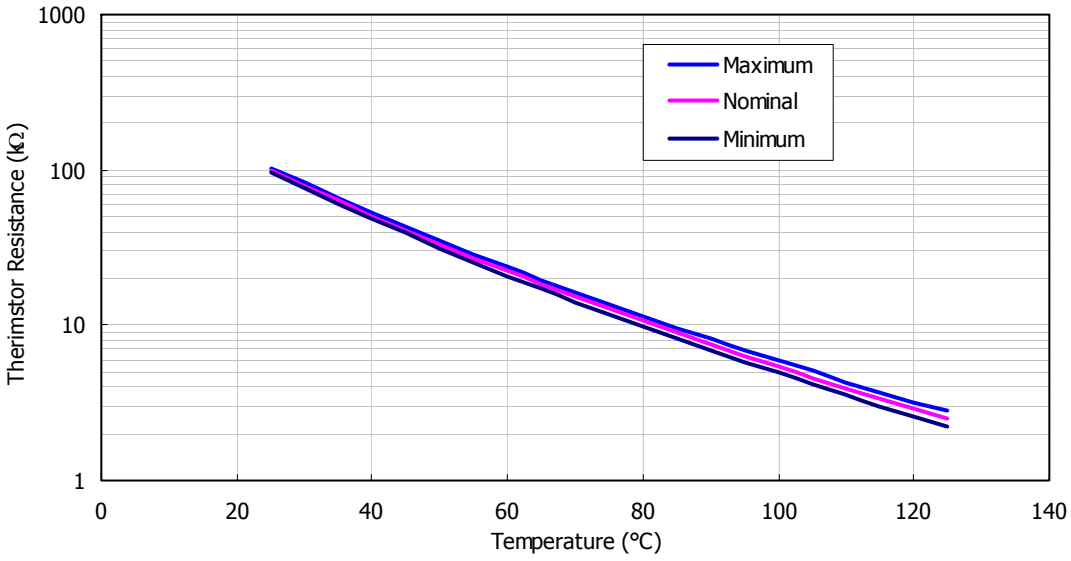


Figure 7. Variation of thermistor resistance with temperature

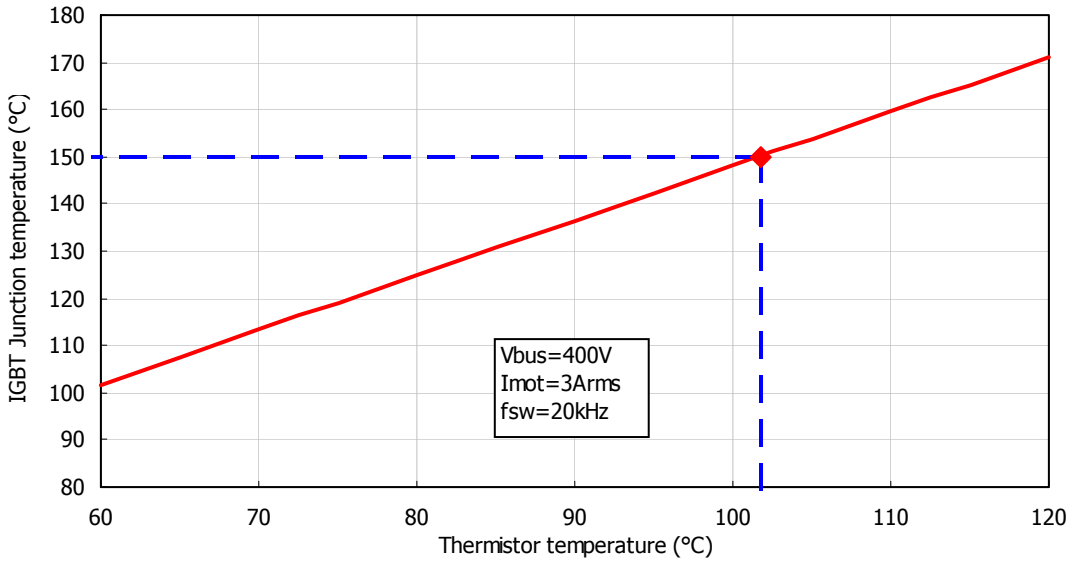


Figure 8. Estimated maximum IGBT junction temperature with thermistor temperature

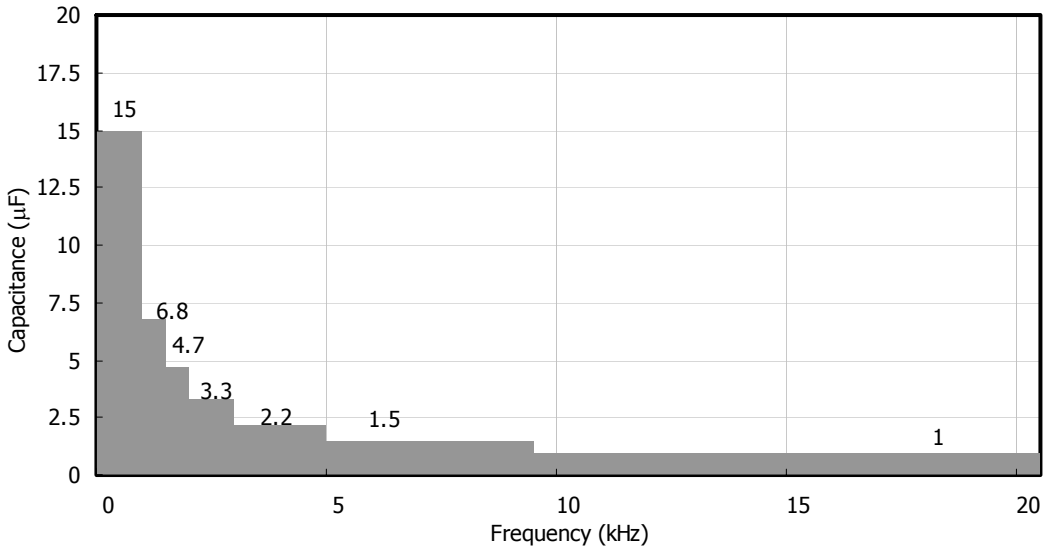


Figure 9. Recommended minimum Bootstrap Capacitor value Vs Switching Frequency

Figure 11. Switching Parameter Definitions

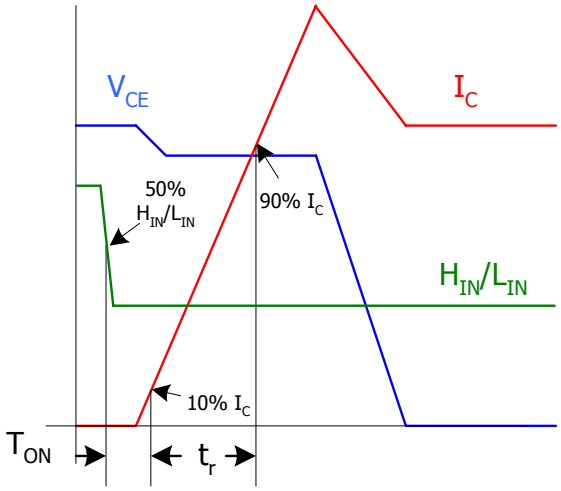


Figure 11a. Input to Output propagation turn-on delay time

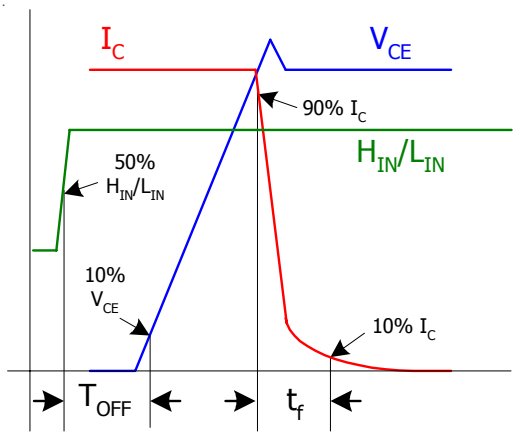


Figure 11b. Input to Output propagation turn-off delay time

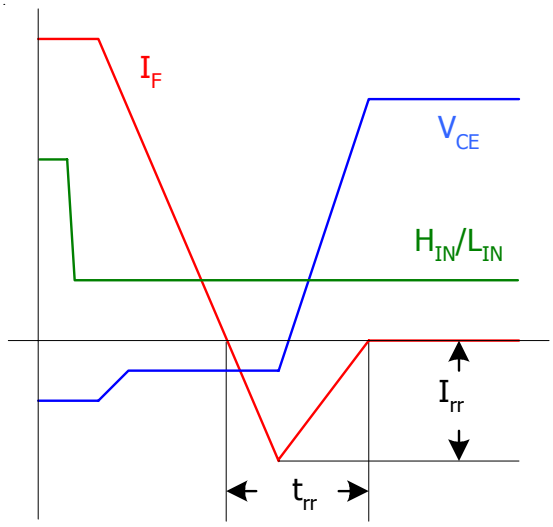


Figure 11c. Diode Reverse Recovery

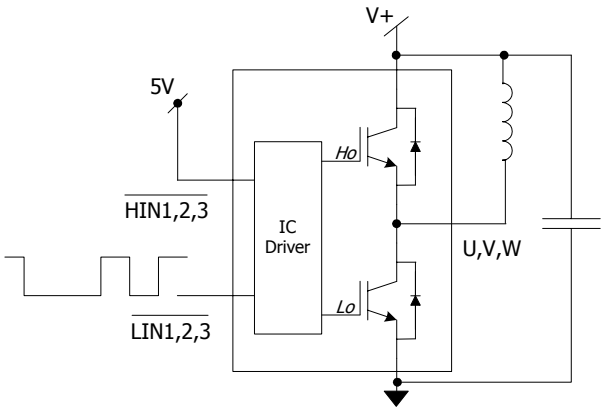
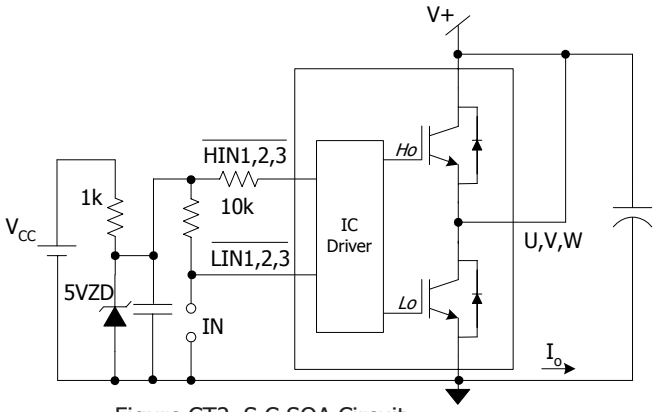
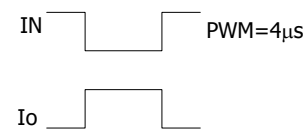


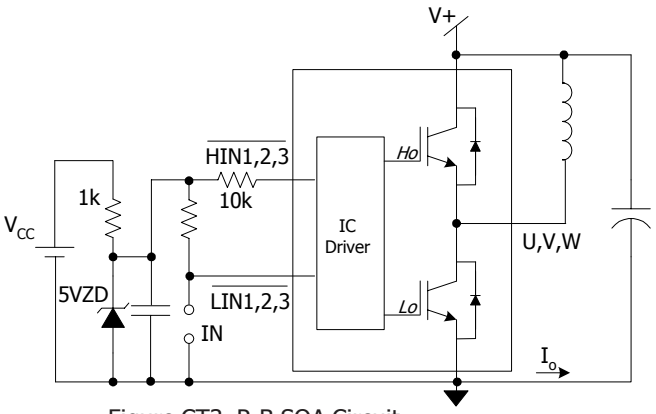
Figure CT1. Switching Loss Circuit

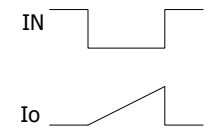




V_P=Peak Voltage on the IGBT die

Figure CT2. S.C.SOA Circuit

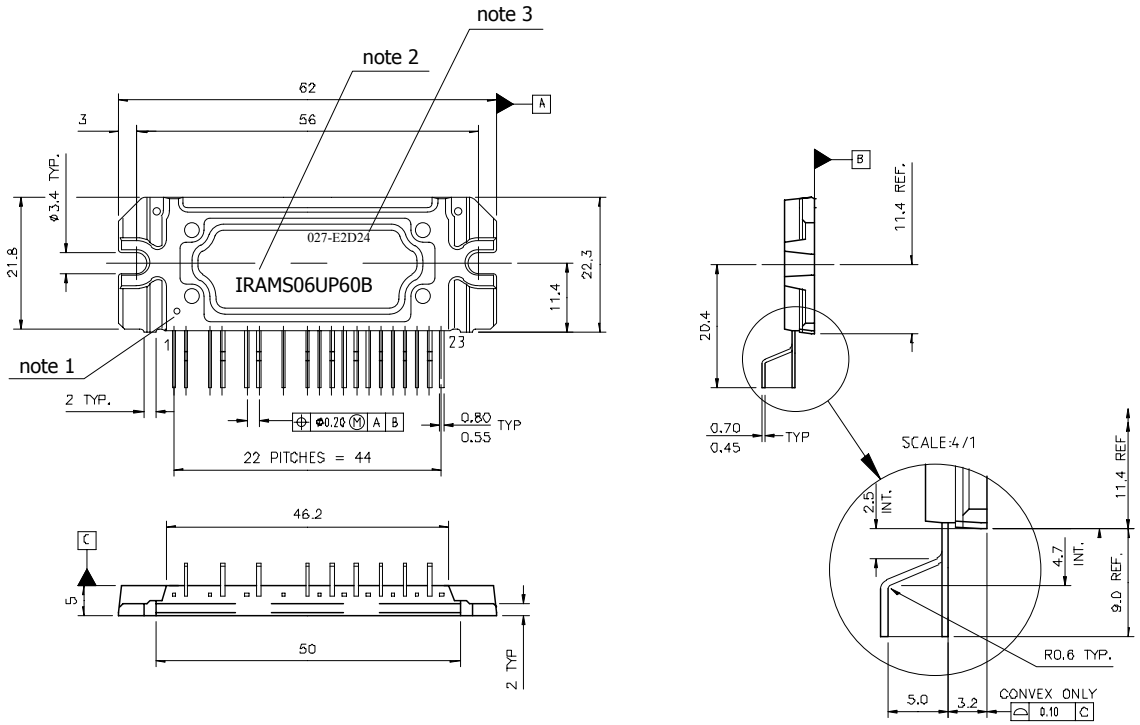




V_P=Peak Voltage on the IGBT die

Figure CT3. R.B.SOA Circuit

Package Outline

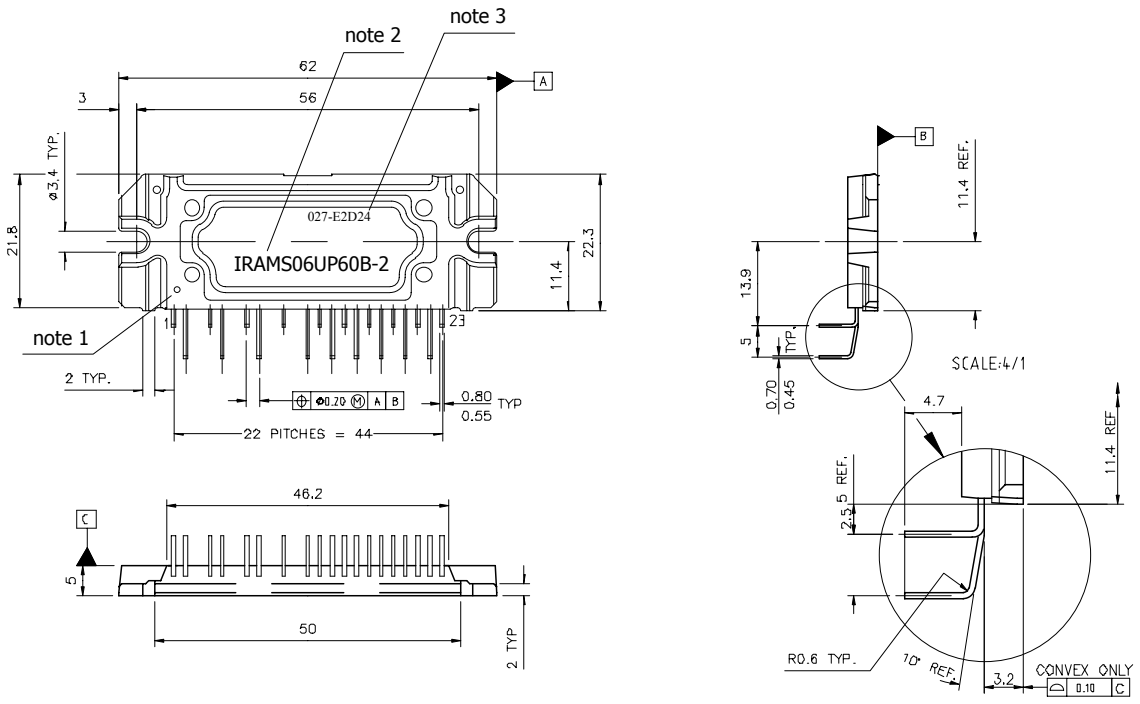


Standard pin leadforming option

Notes:
Dimensions in mm
1- Marking for pin 1 identification
2- Product Part Number
3- Lot and Date code marking

For mounting instruction, see AN1049

Package Outline



Pin leadforming option -2

Notes:
Dimensions in mm
1- Marking for pin 1 identification
2- Product Part Number
3- Lot and Date code marking

Data and Specifications are subject to change without notice

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- *Конкурентоспособные цены и скидки постоянным клиентам.*
- *Специальные условия для постоянных клиентов.*
- *Подбор аналогов.*
- *Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.*

- *Приемлемые сроки поставки, возможна ускоренная поставка.*
- *Доставку товара в любую точку России и стран СНГ.*
- *Комплексную поставку.*
- *Работу по проектам и поставку образцов.*
- *Формирование склада под заказчика.*

- *Сертификаты соответствия на поставляемую продукцию (по желанию клиента).*
- *Тестирование поставляемой продукции.*
- *Поставку компонентов, требующих военную и космическую приемку.*
- *Входной контроль качества.*
- *Наличие сертификата ISO.*

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- *Регистрацию проекта у производителя компонентов.*
- *Техническую поддержку проекта.*
- *Защиту от снятия компонента с производства.*
- *Оценку стоимости проекта по компонентам.*
- *Изготовление тестовой платы монтаж и пусконаладочные работы.*

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